

AP2305D

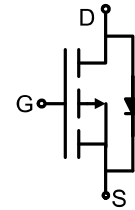
P-Channel Enhancement Mosfet

AIIPOWER

DATA SHEET

Feature

- -20V,-4A
 $R_{DS(ON)} < 47m\Omega @ V_{GS} = -4.5V$ TYP: 37 m Ω
 $R_{DS(ON)} < 60m\Omega @ V_{GS} = -2.5V$ TYP: 45 m Ω
- Advanced Trench Technology
- Lead free product is acquired



Schematic diagram

Application

- Interfacing Switching
- Load Switching
- Power management



SOT-23 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
2305D	AP2305D	Sot-23	7 inch	-	3000

ABSOLUTE MAXIMUM RATINGS ($T_j=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current ($T_j = 25^\circ\text{C}$)	I_D	-4	A
Continuous Drain Current ($T_j = 70^\circ\text{C}$)	I_D	-2.8	A
Pulsed Drain Current	I_{DM}	-16	A
Power Dissipation	P_D	1.25	W
Thermal Resistance from Junction to Ambient ⁽⁴⁾	$R_{\theta JA}$	100	$^\circ\text{C/W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^\circ\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise noted)

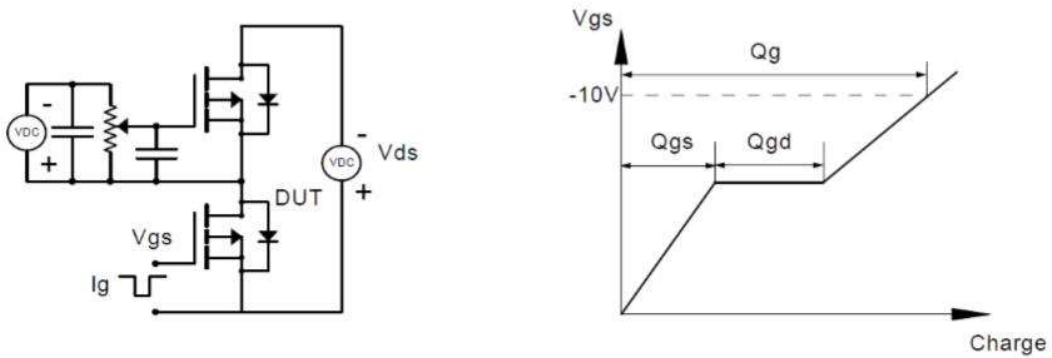
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-20	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -20V, V_{GS} = 0V$	-	-	1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0V$	-	-	± 100	nA
Gate threshold voltage ⁽³⁾	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.45	-0.65	-1.0	V
Drain-source on-resistance ⁽³⁾	$R_{DS(on)}$	$V_{GS} = -4.5V, I_D = -3A$	-	37	47	m Ω
		$V_{GS} = -2.5V, I_D = -2A$	-	45	60	
Dynamic characteristics						
Input Capacitance	C_{iss}	$V_{DS} = -10V, V_{GS} = 0V, f = 1MHz$	-	780	-	pF
Output Capacitance	C_{oss}		-	87	-	
Reverse Transfer Capacitance	C_{rss}		-	81	-	
Switching characteristics						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -10V, I_D = -1A,$ $V_{GS} = -10V, R_G = 3\Omega$	-	7.6	-	ns
Turn-on rise time	t_r		-	14	-	
Turn-off delay time	$t_{d(off)}$		-	40	-	
Turn-off fall time	t_f		-	20	-	
Total Gate Charge	Q_g	$V_{DS} = -10V, I_D = -1A,$ $V_{GS} = -10V$	-	10	-	nC
Gate-Source Charge	Q_{gs}		-	1.5	-	
Gate-Drain Charge	Q_{gd}		-	2.4	-	
Source-Drain Diode characteristics						
Diode Forward voltage ⁽³⁾	V_{DS}	$V_{GS} = 0V, I_S = -4A$	-	-	1.2	V
Diode Forward current ⁽⁴⁾	I_S		-	-	-4	A

Notes:

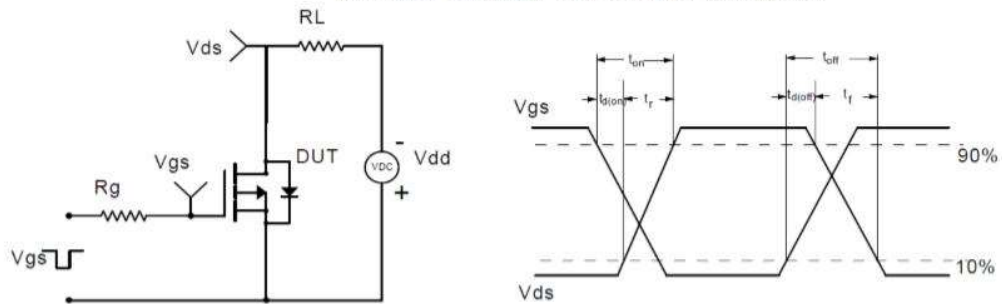
1. Repetitive Rating: pulse width limited by maximum junction temperature
2. Pulse Test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
3. Surface Mounted on FR4 Board, $t_s \leq 10$ sec

Test Circuit

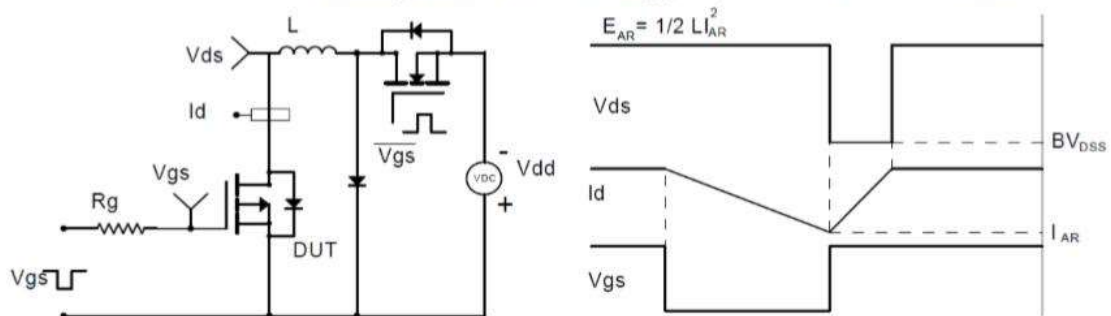
Gate Charge Test Circuit & Waveform



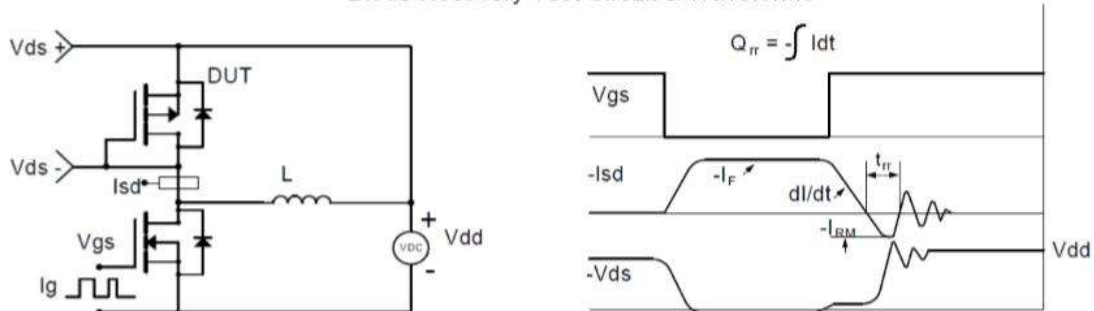
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms



■ Typical Electrical and Thermal Characteristics Diagrams

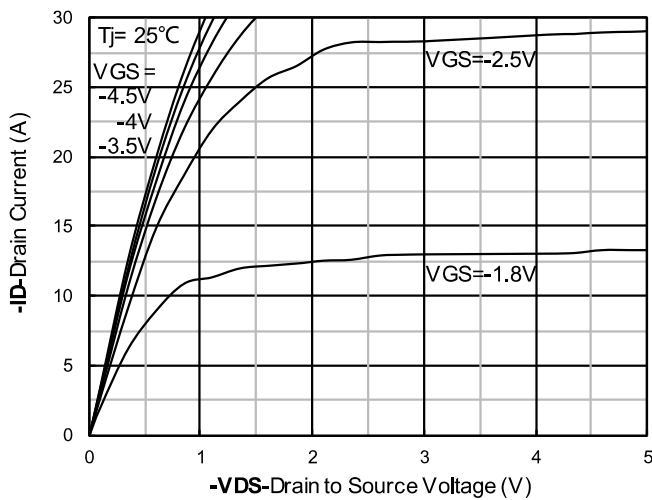


Figure 1. Output Characteristics

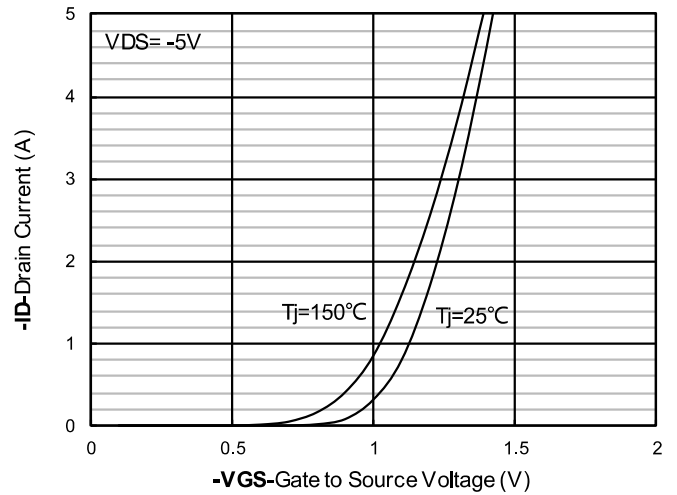


Figure 2. Transfer Characteristics

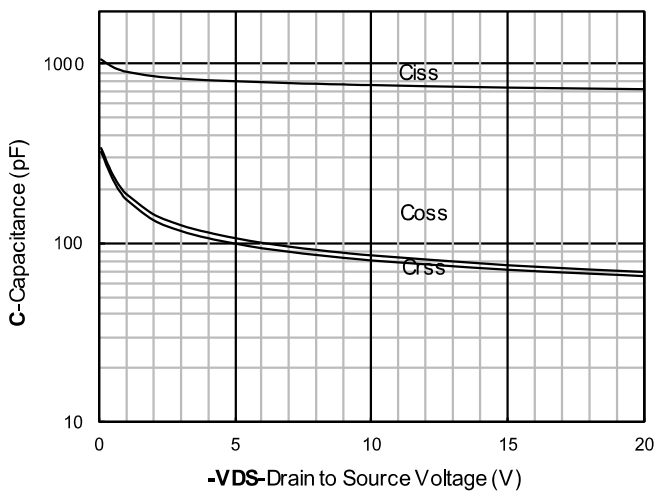


Figure 3. Capacitance Characteristics

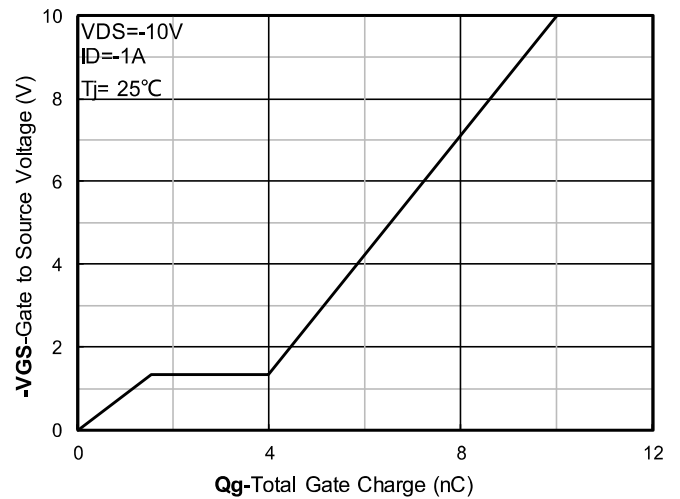


Figure 4. Gate Charge

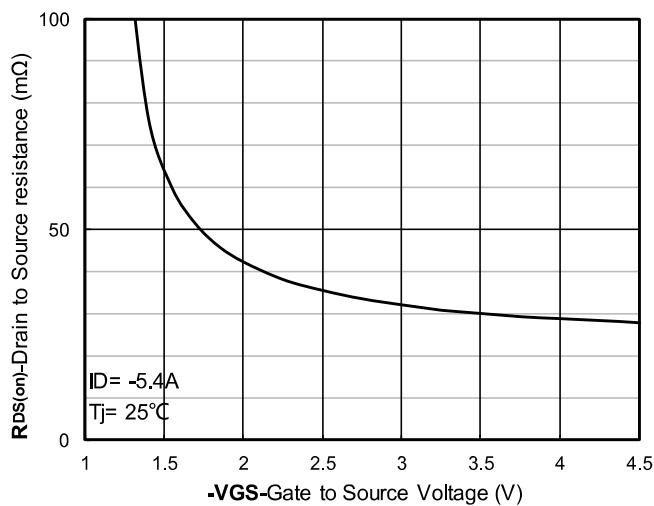


Figure 5. On-Resistance vs Gate to Source Voltage

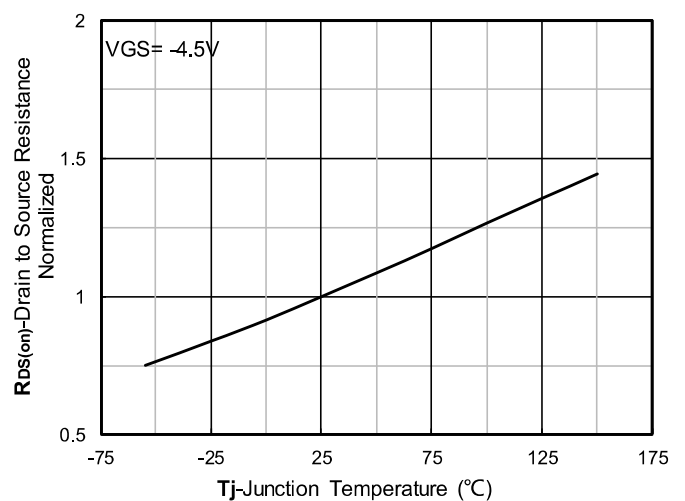


Figure 6. Normalized On-Resistance

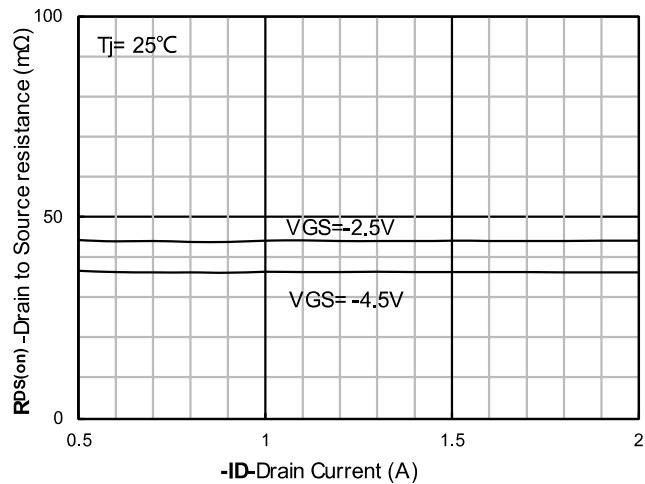


Figure 7. $R_{DS(on)}$ VS Drain Current

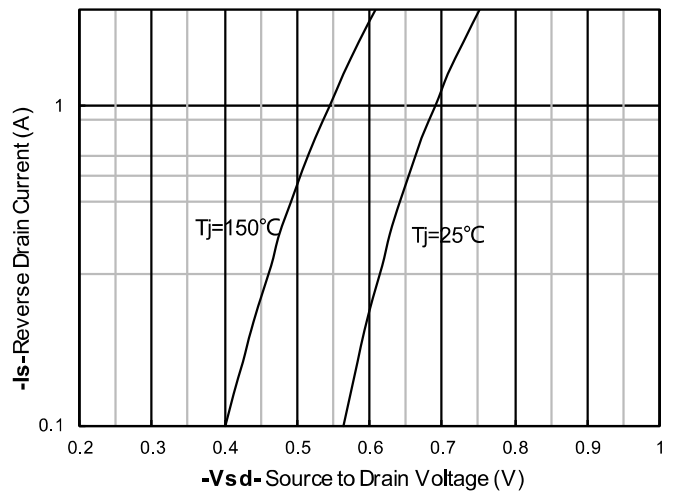


Figure 8. Forward characteristics of reverse diode

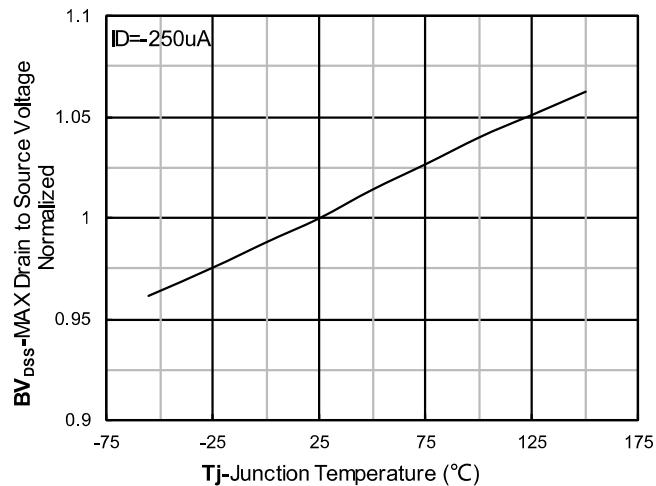


Figure 9. Normalized breakdown voltage

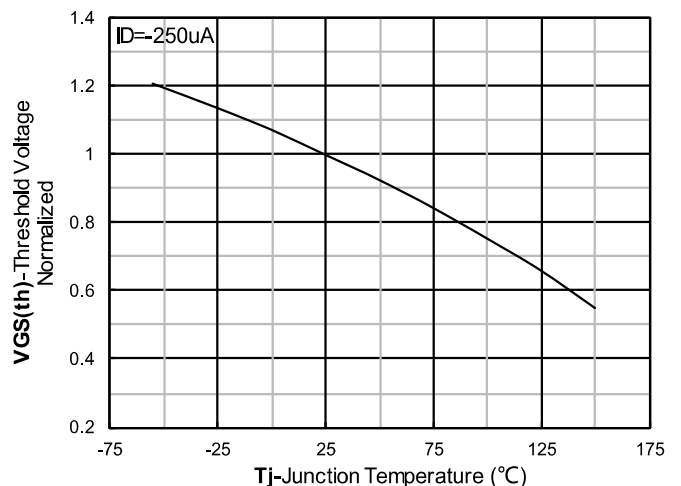


Figure 10. Normalized Threshold voltage

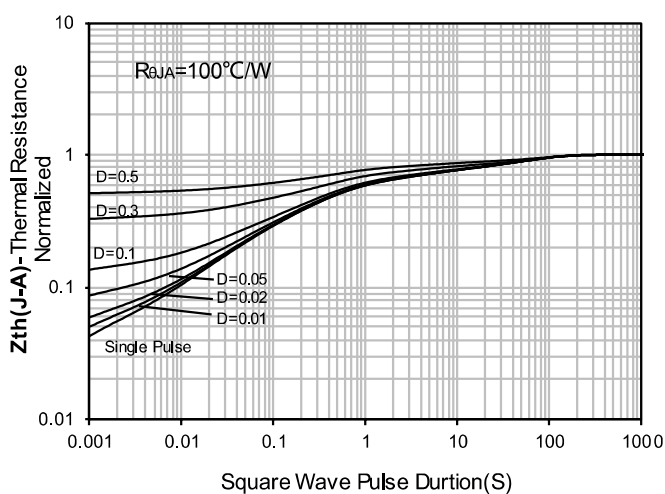


Figure 11. Maximum Transient Thermal Impedance

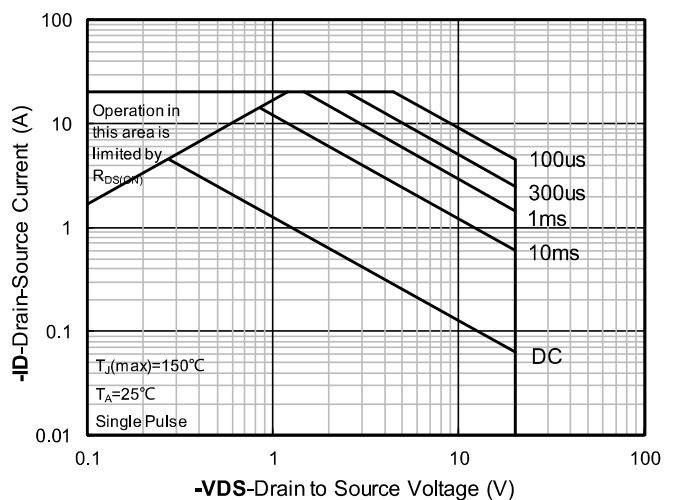
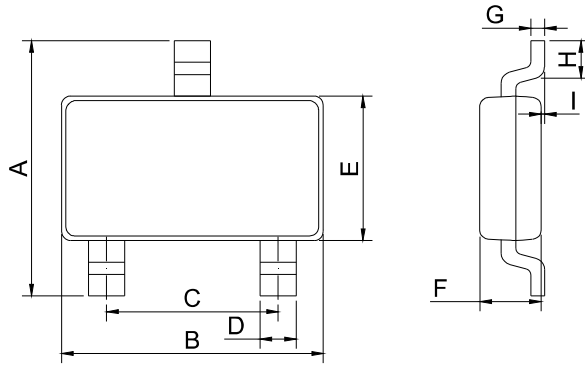


Figure 12. Safe Operation Area

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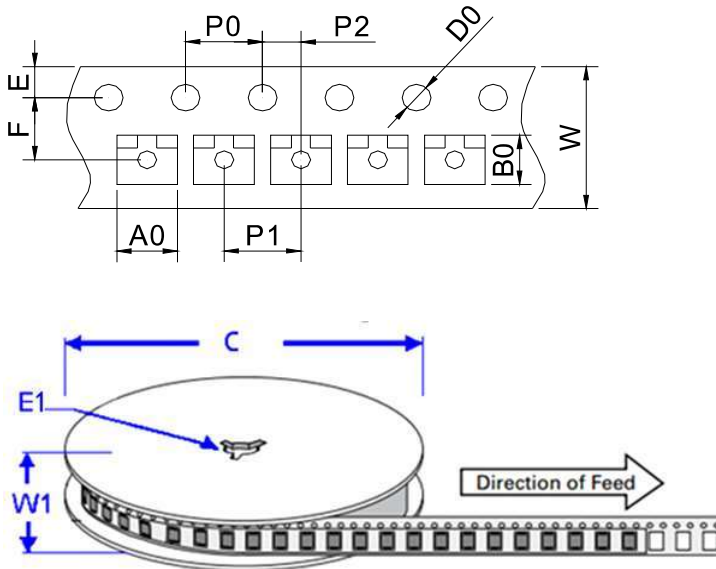
SOT-23 Package Information



SOT-23

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.30	2.40	2.50	0.091	0.095	0.098
B	2.80	2.90	3.00	0.110	0.114	0.118
C	1.90 REF			0.075 REF		
D	0.35	0.40	0.45	0.014	0.016	0.018
E	1.20	1.30	1.40	0.047	0.051	0.055
F	0.90	1.00	1.10	0.035	0.039	0.043
G		0.10	0.15		0.004	0.006
H	0.20			0.008		
I	0		0.10	0		0.004

Package Information-SOT-23



Ref.	Dimensions	
	Millimeters	Inches
A0	3.15 ± 0.3	0.124 ± 0.012
B0	2.77 ± 0.3	0.109 ± 0.012
C	178	7.0
D0	1.50 ± 0.1	0.059 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524 ± 0.012
F	3.5 ± 0.2	0.138 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	8.00 ± 0.2	0.315 ± 0.008
W1	11.5 ± 1.0	0.453 ± 0.039

Revision History

Revision	Release	Remark
V1.1	2023/11/01	Initial Release

Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

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